

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L10	8	GaN-based and (insulat\$3 or dielectric) with ((oxy near nitride or oxynitride or "SiON") and (silicon dioxide or "SiO.sub.2") and "SiN")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/12/10 15:48
L11	115	GaN-based and (insulat\$3 or dielectric) with ((oxy near nitride or oxynitride or "SiON") or (silicon dioxide or "SiO.sub.2") and "SiN")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/12/10 16:31
L12	107	11 not 10	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/12/10 15:48
L19	1898	(oxy near nitride or oxynitride or "SiON") and "GaN" and @pd<"20040220"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/12/10 16:19
L23	316	GaN and ((silicon dioxide or "SiO.sub.2") and "SiN") and @pd<"20040220"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/12/10 16:51
S10	207	(shirai near koji).in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/12/08 13:51
S60	10392	((257/368,410,411,E21.345,E21.345,E29.133,E29.255,E29.054,E21.433) or (438/299,257,766)).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/12/09 13:58

## EAST Search History

S61	132	S60 and (oxide or nitride or insulat\$3 or dielectric) with (thick and thin or stepped or stepwise or stair or ramped or tapered) portion	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/12/09 14:01
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